С		Reg. No. :										
Question Paper Code: U2425												
B.E./B.Tech. DEGREE EXAMINATION, NOV 2022												
Second Semester												
Computer Science and Business Systems												
21UEC225- Principles Of Electronics Engineering												
(Regulations 2021)												
Dura	ation: Three hours						Max	imum	: 100	Maı	rks	
Answer All Questions												
PART A - $(5x 1 = 5 \text{ Marks})$												
1.	The efficiency of half wave rectifier is?									CO	1 - U	
	(a) 100%	(b) 90%		(c) 81	.2%		(d) 42	.5%				
2.	In an NPN transistor, the arrow is pointed towards								CO	1- U		
	(a) the collector (b	b) the base (c) of	depends	on the c	onfigur	ation	(d)	the er	nitter			
3.	The SI Units of the F	Process transcone	ductance	e Parame	eter (k')	is				CO	1- R	
	(a) V2/A (b	o) A/V2		(c) V/	A		(d	l) A/V	r			
4.	Which of the following gate is called universal gate?							CO	2- U			
	(a) AND	(b) OR		(c) X	OR	(0	l) NAI	ND				
5.	The truth table for an	n S-R flip-flop h	as how 1	many VA	ALID ei	ntries?)			CO	2- U	
	(a) 1	(b) 2		(c) 3			(d) 4					
PART - B (5 x 3 = 15 Marks)												
6.	Calculate the ripple factor of full wave rectifier if Vm=20V							CO3- App				
7.	List out the transistor H-parameters							CO1- U				
8.	Difference between BJT and JFET.							CO1- U				
9.	Implement the half adder using OR gate							CO4- App				
10.	Differentiate SIPO and PIPO ?							CO2- U				

PART – C (5 x 16= 80Marks)

11.	(a)	Design a half wave rectifier using PN diode and calculate ripple factor and efficiency	CO3-App	(16)
		Or		
	(b)	Compare Half wave, Full wave and Bridge rectifier.	CO6-Ana	(16)
12.	(a)	Analyze impedance, admittance and gain of transistors to design amplifier with suitable configuration Or	CO6-Ana	(16)
	(b)	Relate CB, CC and CE configuration to find current amplification factor with suitable expression	CO6-Ana	(16)
13.	(a)	Explain the construction, working and operating characteristics of P-channel JFET with relevant diagrams. Or	CO1-U	(16)
	(b)	Explain the principle of operation of enhancement P-channel MOSFET and draw its drain characteristics.	CO1-U	(16)
14.	(a)	Design a binary-to-gray code converter and gray to binary code converter similar to basic ROM Structure Or	CO4-App	(16)
	(b)	Design a binary-to- BCD converter and BCD to binary code converter similar to basic ROM Structure	CO4-App	(16)
15.	(a)	Design PISO and PIPO shift register using D flipflop. Or	CO4-App	(16)
	(b)	Analyze the use of up /down counter in radar applications	CO5-Ana	(16)